

Topical reviews

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2. E.L. Ivchenko and S.D. Ganichev,
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3. S. D. Ganichev, D. Weiss, and J. Eroms,
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4. G. V. Budkin, L. E. Golub, E. L. Ivchenko, and S. D. Ganichev,
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7. M.M. Glazov and S.D. Ganichev
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8. E. L. Ivchenko and S. D. Ganichev
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9. S. Dvoretsky, N. Mikhailov, Y. Sidorov, V. Shvets, S. Danilov, B. Wittman, S. Ganichev,
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Spin photocurrents in quantum wells, review,
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16. S.D. Ganichev,
Ionization of impurities in semiconductors by intense FIR radiation, review
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17. S.D. Ganichev, I. N. Yassievich, and W. Prettl
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18. S.D. Ganichev,
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